

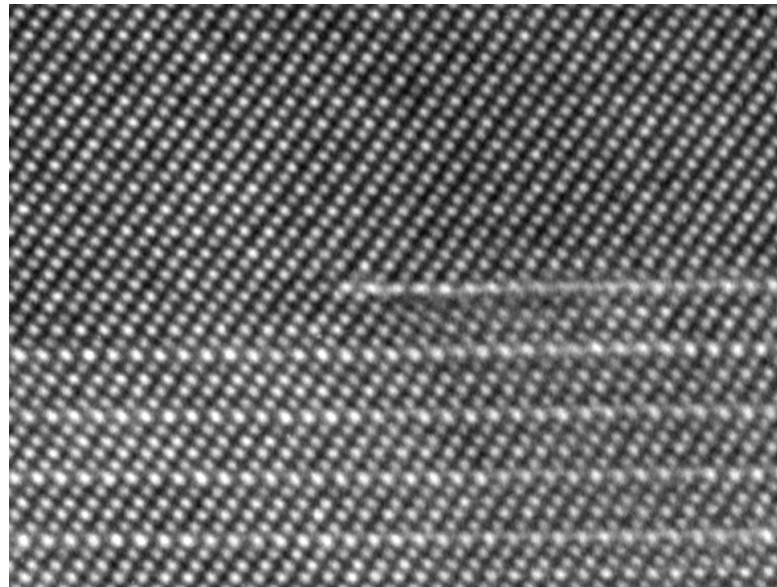
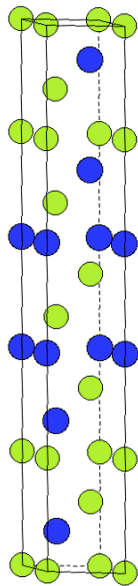
Interfacial Structure in Telluride-Based Thermoelectric Materials

SAND2011-4856C

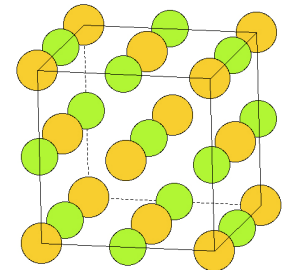
Douglas L. Medlin

**Materials Physics Department
Sandia National Laboratories
Livermore, CA 94551 USA**

Tetradymite



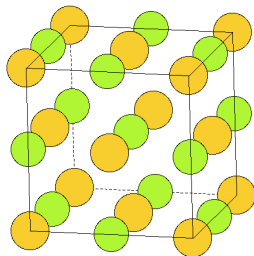
Rock-Salt



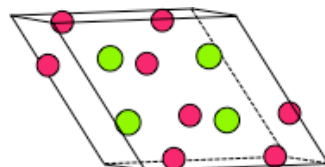
Microstructure in Bulk Thermoelectrics

- Variety of microstructural strategies for bulk thermoelectrics employ embedded interfaces to decouple thermal and electronic transport
- Solid-state phase transformations provide one route to embedding interfaces
- *Our focus:*
Establish the atomic mechanisms that govern formation and stability of embedded interfaces in nanostructured thermoelectrics.
- *Thermoelectric Tellurides:*
Rich set of structures and phase relations

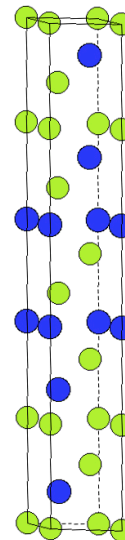
Rock-Salt
(PbTe, AgSbTe₂)



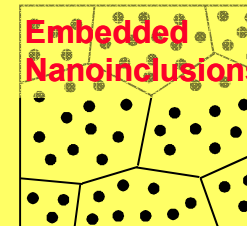
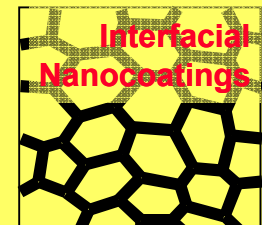
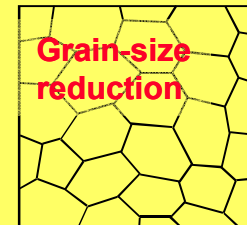
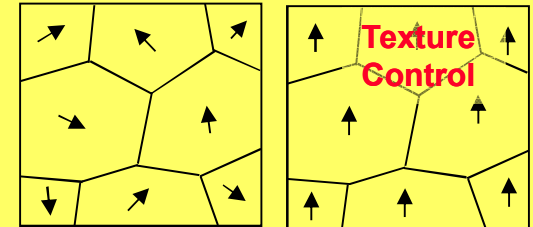
Monoclinic
(Ag₂Te)



Tetradymite
(Bi₂Te₃, Sb₂Te₃)



Microstructural Strategies for Nanostructured Bulk Thermoelectrics

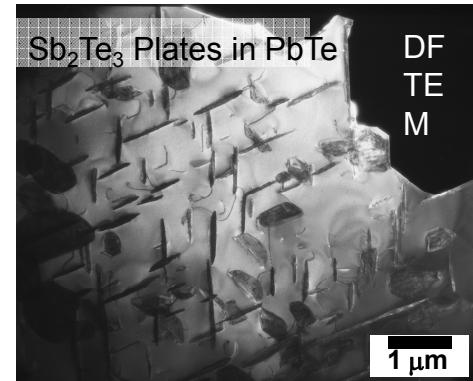


Medlin and Snyder, Current Opinion in Colloid and Interface Science, 2009

Outline

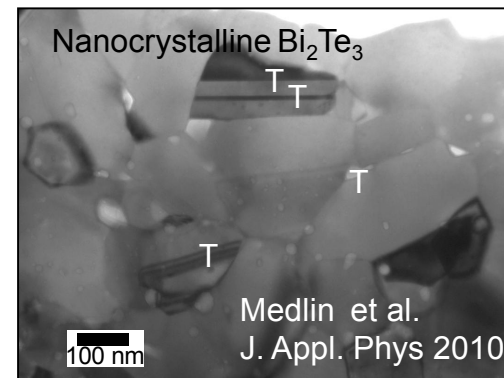
•Rocksalt/Tetradymite Telluride Interfaces

- AgSbTe₂/Sb₂Te₃
- PbTe/Sb₂Te₃
- Tetradymite plate formation.
- Interfacial strain accommodation.



• Structure of the basal twin in Bi₂Te₃

- What is the compositional termination?
- Structural relaxations?
- Formation mechanism?



Collaborators

Sandia:

Josh Sugar
Jessica Lensch-Falk
Nancy Yang
Catalin Spataru
Michelle Hekmaty
Mark Homer

Caltech:

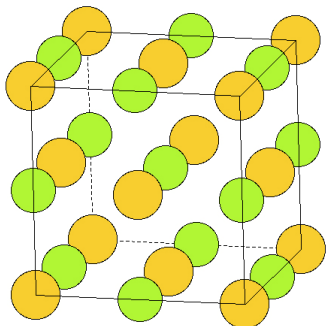
Nick Heinz
Teruyuki Ikeda
G. Jeffrey Snyder

LBNL:

Quentin Ramasse

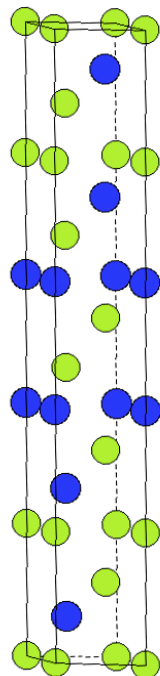
Heterophase Rock-Salt/Tetradymite Telluride Interfaces

Rock-Salt
(PbTe, AgSbTe₂)



Fm-3m

Tetradymite
(Bi₂Te₃, Sb₂Te₃)



R-3m

-Interest in forming thermoelectric nanocomposites of rock-salt and tetradymite tellurides:

- Possibility for well ordered interfaces.
- Transformations provide bulk route to synthesis.

Ikeda, et al., Chem Mater. 2007

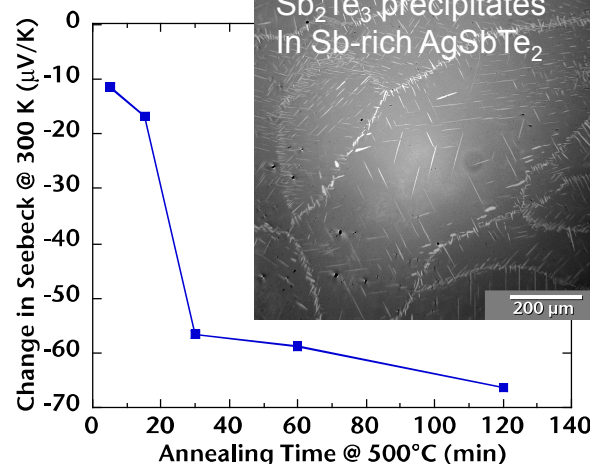
Snyder and Toberer, Nature Materials 2008

-AgSbTe₂:

- Constituent of TAGS (GeTe)_x(AgSbTe₂)_{1-x} and LAST (PbTe)_x(AgSbTe₂)_{1-x} $zT \sim 1.8$

-High performance TE material: $zT > 1.2$

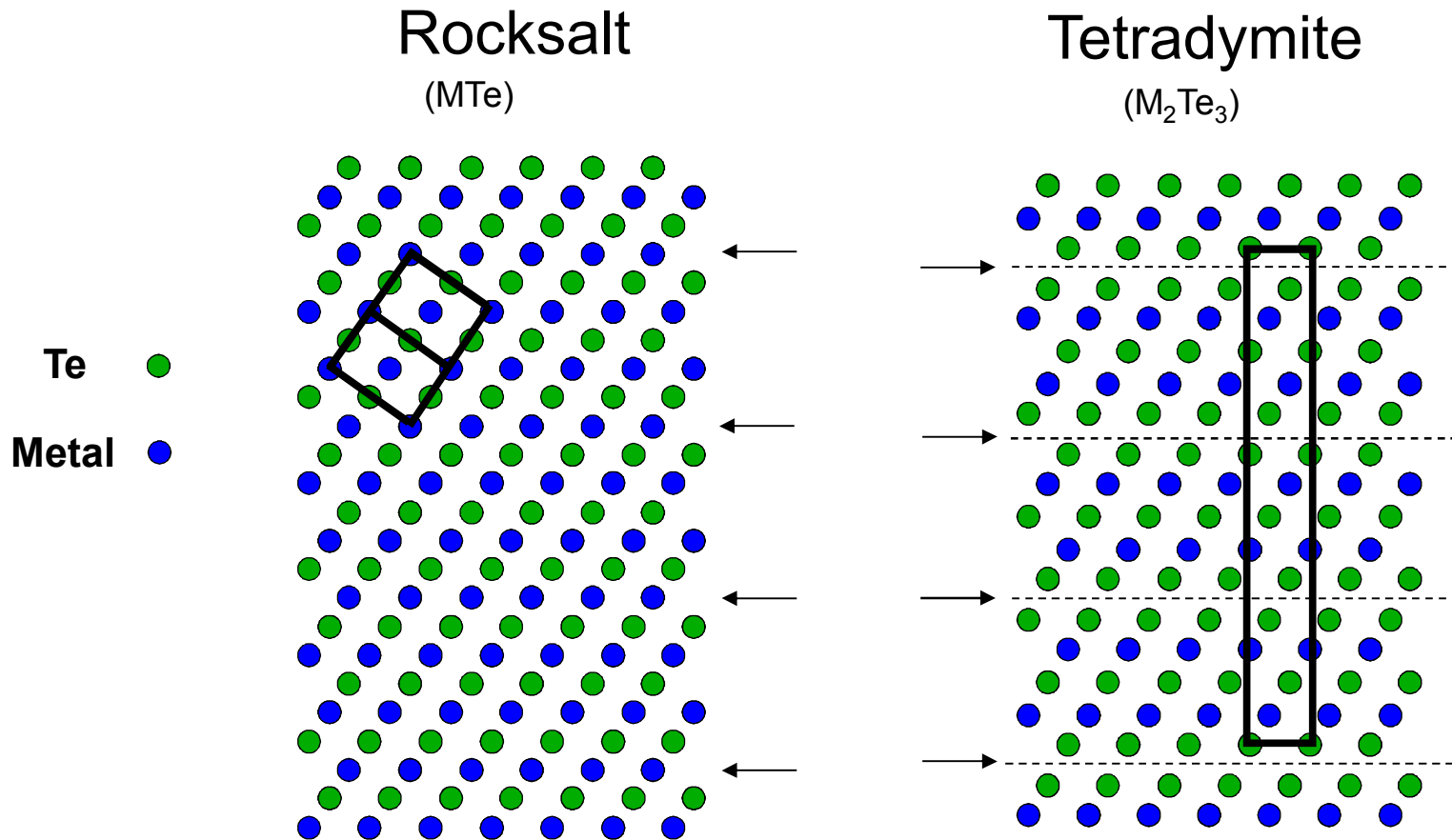
-Degradation of Seebeck coefficient with Sb₂Te₃ precipitation



Sharma, Sugar, Medlin J. Appl. Phys. 2010

What happens at interface?
How do transformations occur?
Misfit accommodation?

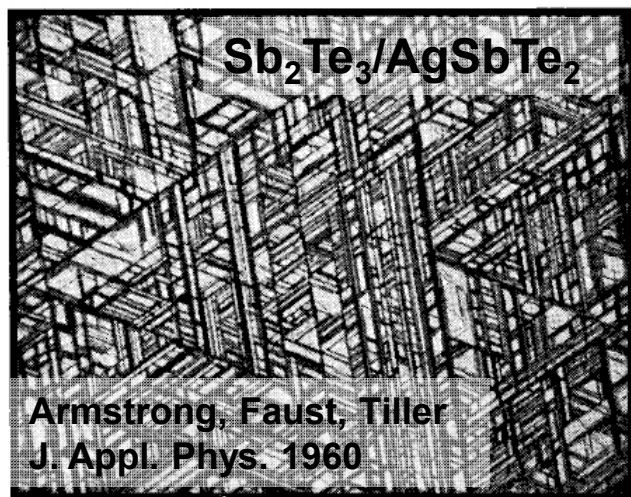
Rocksalt and Tetradymite-structured Tellurides are Closely Related



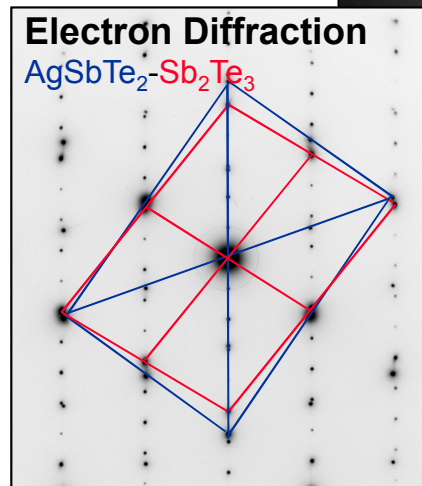
- Remove metal plane every 6 layers
- Shear blocks by $\frac{1}{3}\langle 10-10 \rangle$
(or $\frac{1}{6}\langle 112 \rangle$ relative to cubic coordinates)

Tetradymite Precipitates in rock-salt structured tellurides

Widmanstätten plates

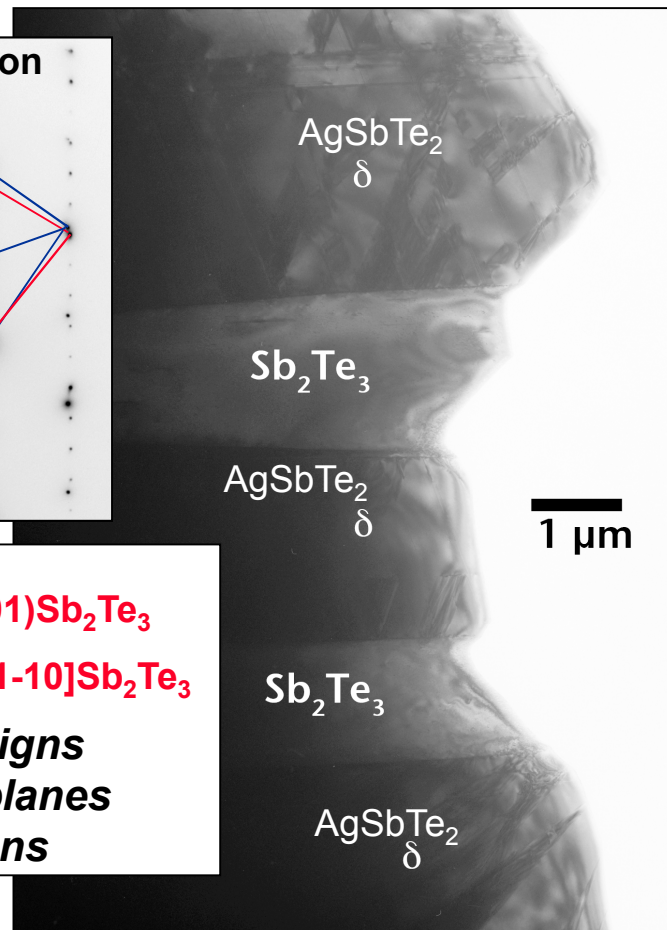


TEM Sb₂Te₃/AgSbTe₂



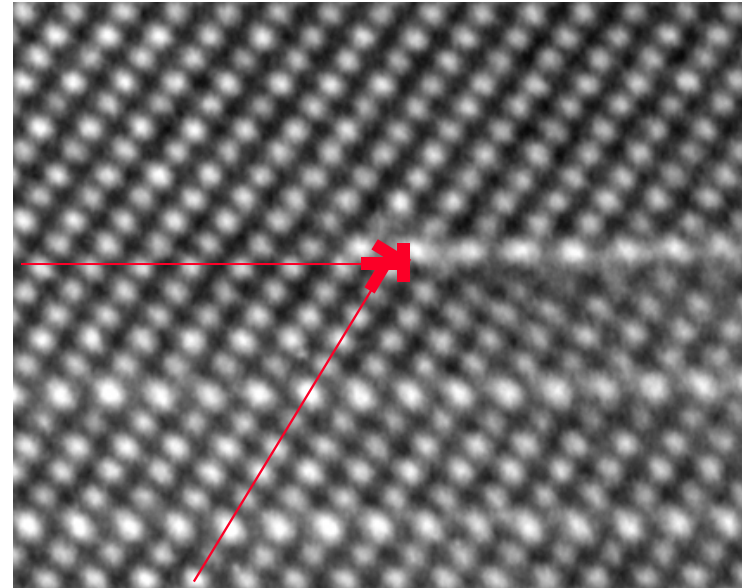
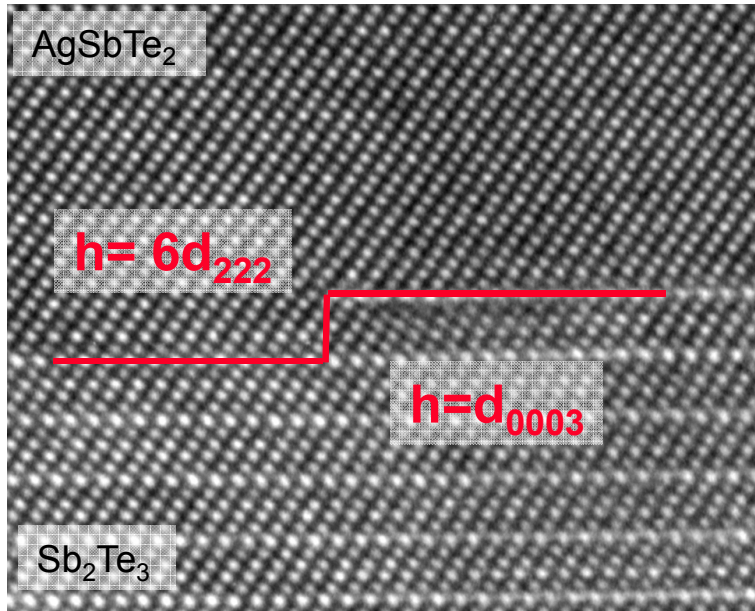
(111)AgSbTe₂ // (0001)Sb₂Te₃
[-101]AgSbTe₂ // [2-1-10]Sb₂Te₃

*Orientation aligns
close-packed planes
and directions*



Medlin and Sugar,
Scripta Mat 2010

HRTEM : Step at $\text{AgSbTe}_2/\text{Sb}_2\text{Te}_3$ Interface



Defect has both *step* and *dislocation* character.

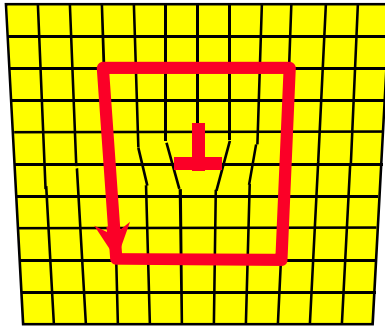
- Interfacial “Disconnection” (e.g. Hirth and Pond, Acta Mat 1996).
- Geometric properties of disconnections control mass flux and structural rearrangements of phase transformations.

Step joins 6 $\{222\}$ planes in AgSbTe_2 with 5 $\{000\ 15\}$ planes in Sb_2Te_3

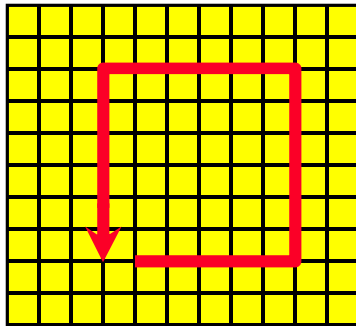
Complex dislocation configuration.

Defining the topological properties of line defects requires a reference frame

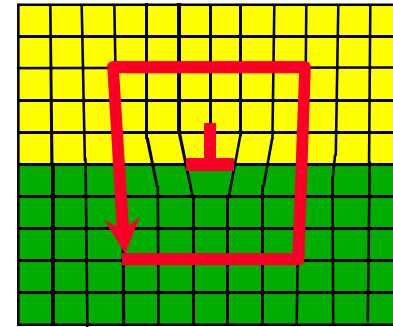
Bulk Lattice Dislocation.



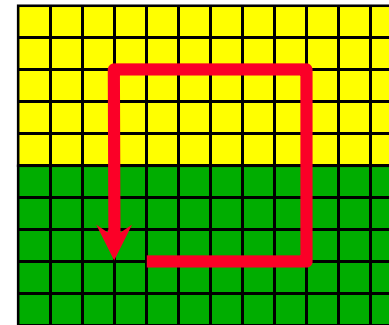
Reference Frame:
Perfect Crystal



Heteroepitaxial Misfit Dislocation.



Reference Frame:
Coherently Strained Interface



Circuit analysis to quantify defect character

Burgers vector:

$$\mathbf{b} = -(\mathbf{C}_\lambda + \mathbf{P}\mathbf{C}_\mu)$$

Upper crystal circuit

Lower crystal circuit

Crystal coordinate transformation

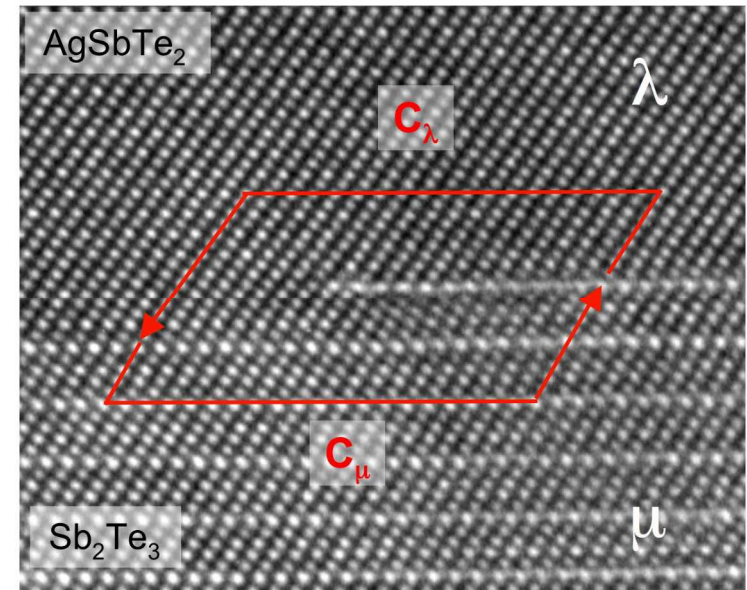
Referenced to Coherent Frame:

Strain to bring μ and λ into coherency

$$\mathbf{P} = \mathbf{L} \mathbf{A} \mathbf{M} = \begin{pmatrix} \frac{1}{2} & \frac{-1}{2} & \frac{c_{hex}}{a_{cub} \sqrt{3}} \\ 0 & \frac{1}{2} & \frac{c_{hex}}{a_{cub} \sqrt{3}} \\ \frac{-1}{2} & 0 & \frac{c_{hex}}{a_{cub} \sqrt{3}} \end{pmatrix}$$

Converts from orthonormal to λ crystal coordinates

Converts from μ crystal coordinates to orthonormal coordinates



Misfit: 0.79%

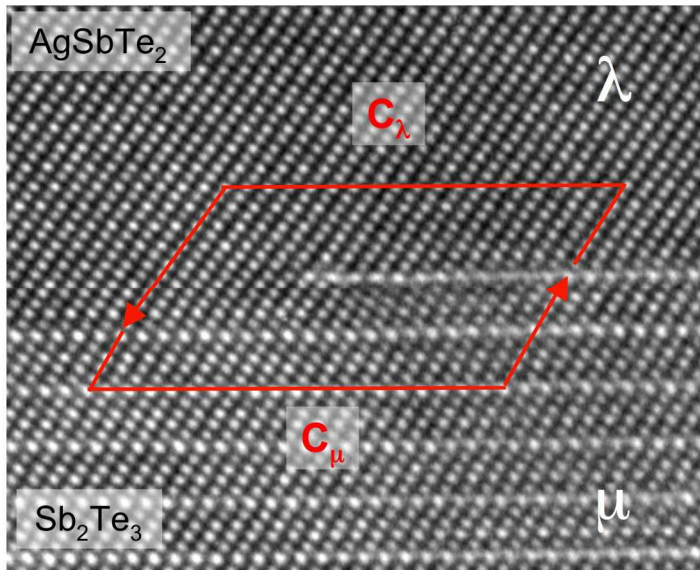
$$r = \frac{1}{\sqrt{2}} \frac{a_{cub}}{a_{hex}} = 1.0079$$

Sb₂Te₃: a=4.264 Å
c=30.458 Å

AgSbTe₂: a=6.078 Å

Role of defect in precipitate growth:

Burgers vector:



Upper crystal circuit

Lower crystal circuit

$$\mathbf{b} = -(\mathbf{C}_\lambda + \mathbf{P}\mathbf{C}_\mu)$$

Coordinate Transformation
From Tetradymite to
Rock-salt reference frame

Resolve $\mathbf{b}$ into components
normal and parallel to interface

$$\mathbf{b}_n = (a_{cub} - c_{hex} / 3\sqrt{3})[111]$$

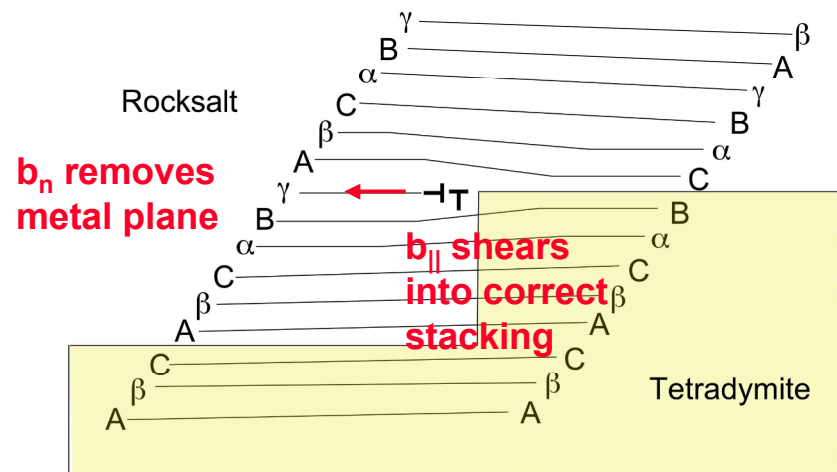
• mismatch of step heights.

$$|\mathbf{b}_n| = 0.3747\text{\AA}$$

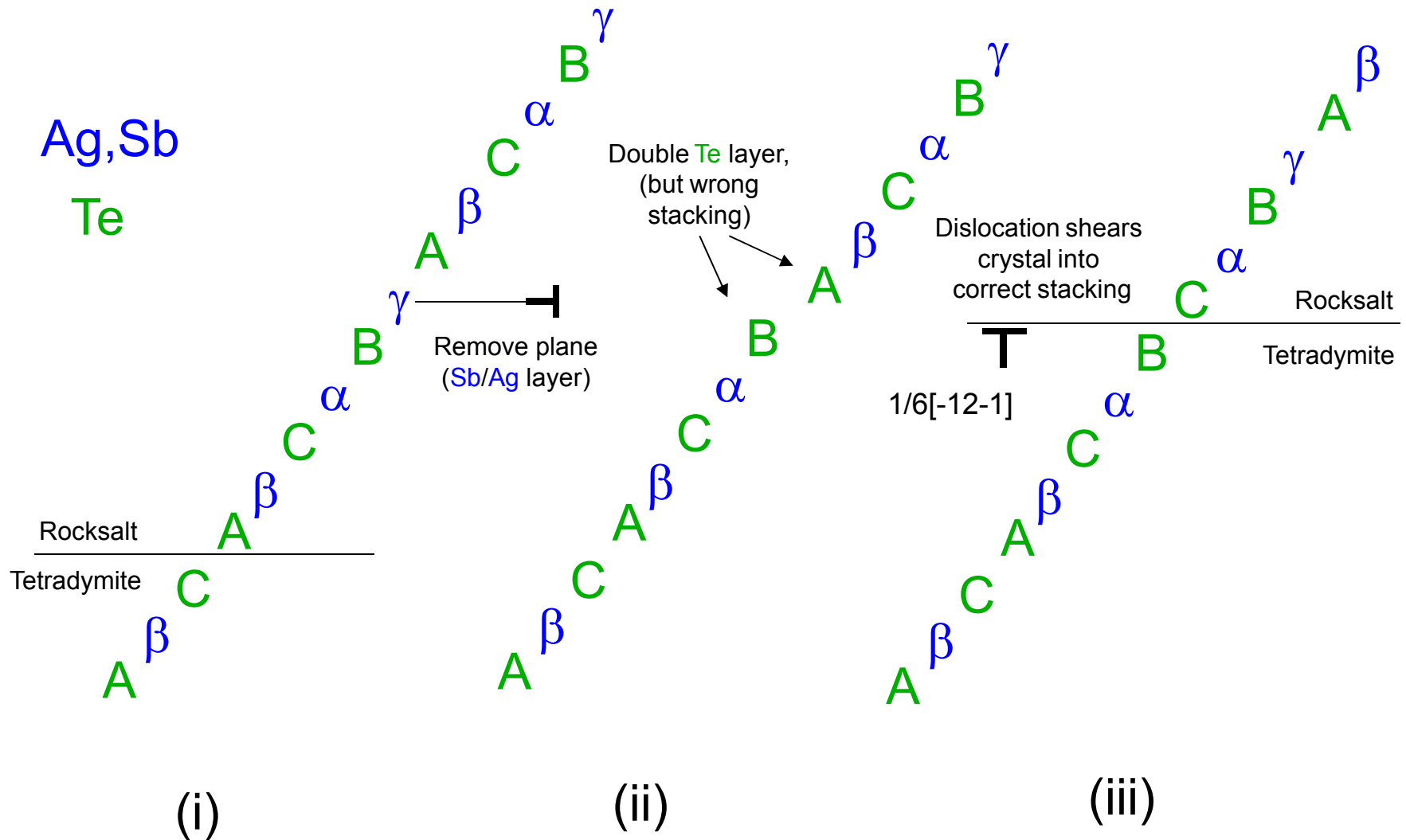
$$\mathbf{b}_\parallel = \frac{a_{cub}}{6}[\bar{1}2\bar{1}]$$

• Analogous to
Shockley partial
Dislocation

$$|\mathbf{b}_\parallel| = 2.48\text{\AA}$$

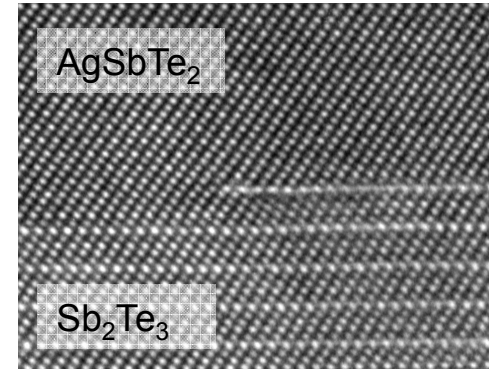
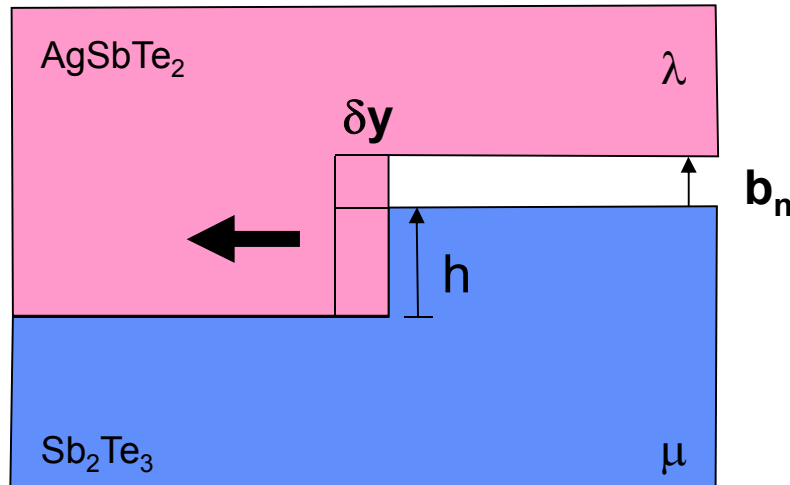


Schematic of Transformation Sequence



Defect properties give local mass flux required for transformation

Partition flux for defect motion into step and dislocation components



$$\frac{\Delta N_i}{L\delta y} = \underbrace{(\chi_i^\lambda - \chi_i^\mu)h}_{\text{step}} + \underbrace{\chi_i^\lambda b_n}_{\text{dislocation}}$$

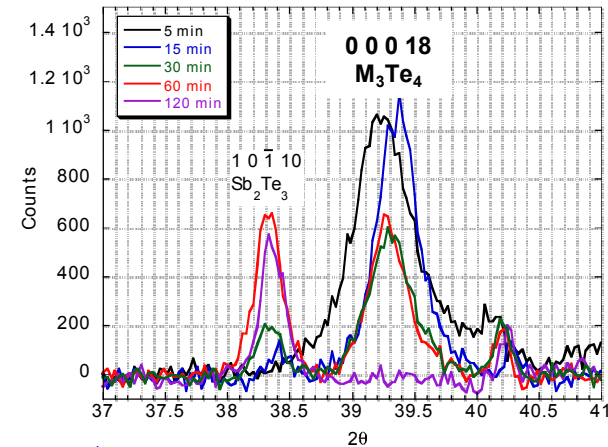
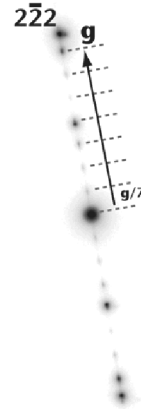
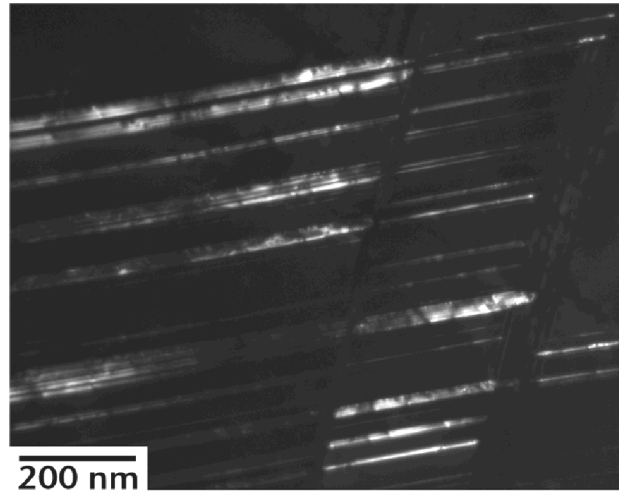
Hirth & Pond, Acta Mat 1996

**Reject Ag and Incorporate Sb
in ratio of 3:1**

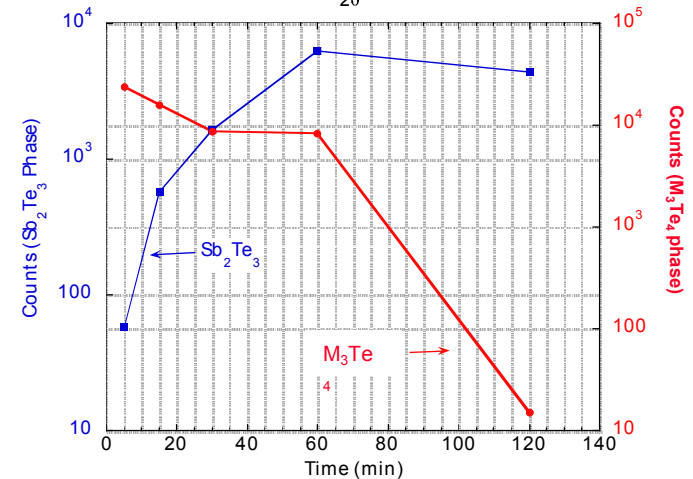
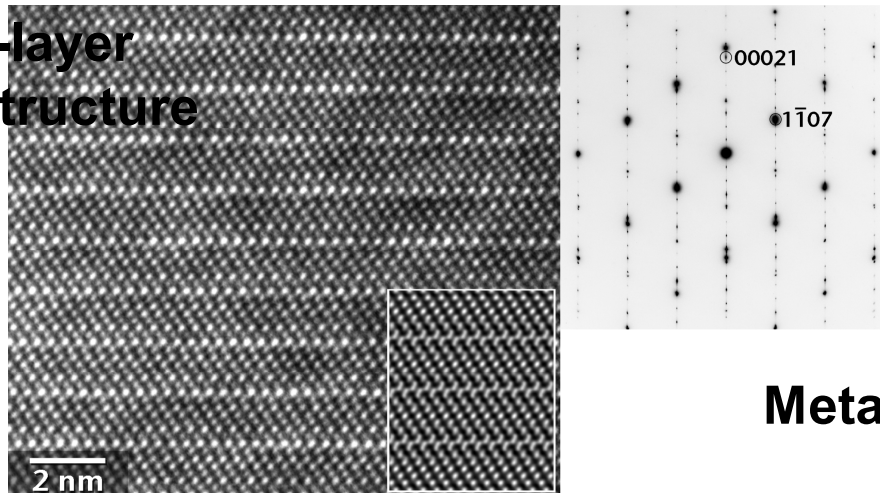
**Tellurium:
Step and Dislocation fluxes cancel.
No long-range Te transport required.**

Species	Step flux (atoms/Å ²)	Dislocation flux (atom/Å ²)	Total flux (atom/Å ²)
Ag	$\frac{2 c_{hex}}{3 a_{cub}^3}$ +0.09043	$\frac{2}{a_{cub}^3}(\sqrt{3}a_{cub} - c_{hex}/3)$ +0.00334	$\frac{2\sqrt{3}}{a_{cub}^2}$ +0.09377
Sb	$\frac{2 c_{hex}}{3 a_{cub}^3} - \frac{8\sqrt{3}}{3 a_{cub}^2}$ -0.03459	$\frac{2}{a_{cub}^3}(\sqrt{3}a_{cub} - c_{hex}/3)$ +0.00334	$-\frac{2\sqrt{3}}{3 a_{cub}^2}$ -0.03126
Te	$-\frac{4}{a_{cub}^3}(\sqrt{3}a_{cub} - c_{hex}/3)$ -0.00668	$+\frac{4}{a_{cub}^3}(\sqrt{3}a_{cub} - c_{hex}/3)$ +0.00668	0

Initial Stages of Precipitation: Transition Phase: $(\text{Ag,Sb})_3\text{Te}_4$



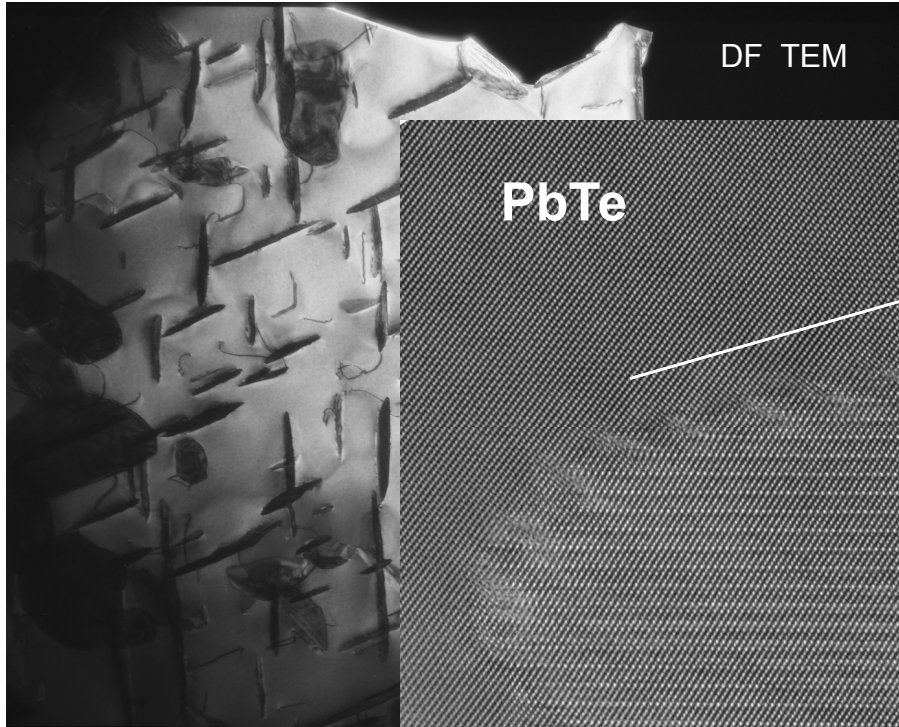
7-layer
Structure



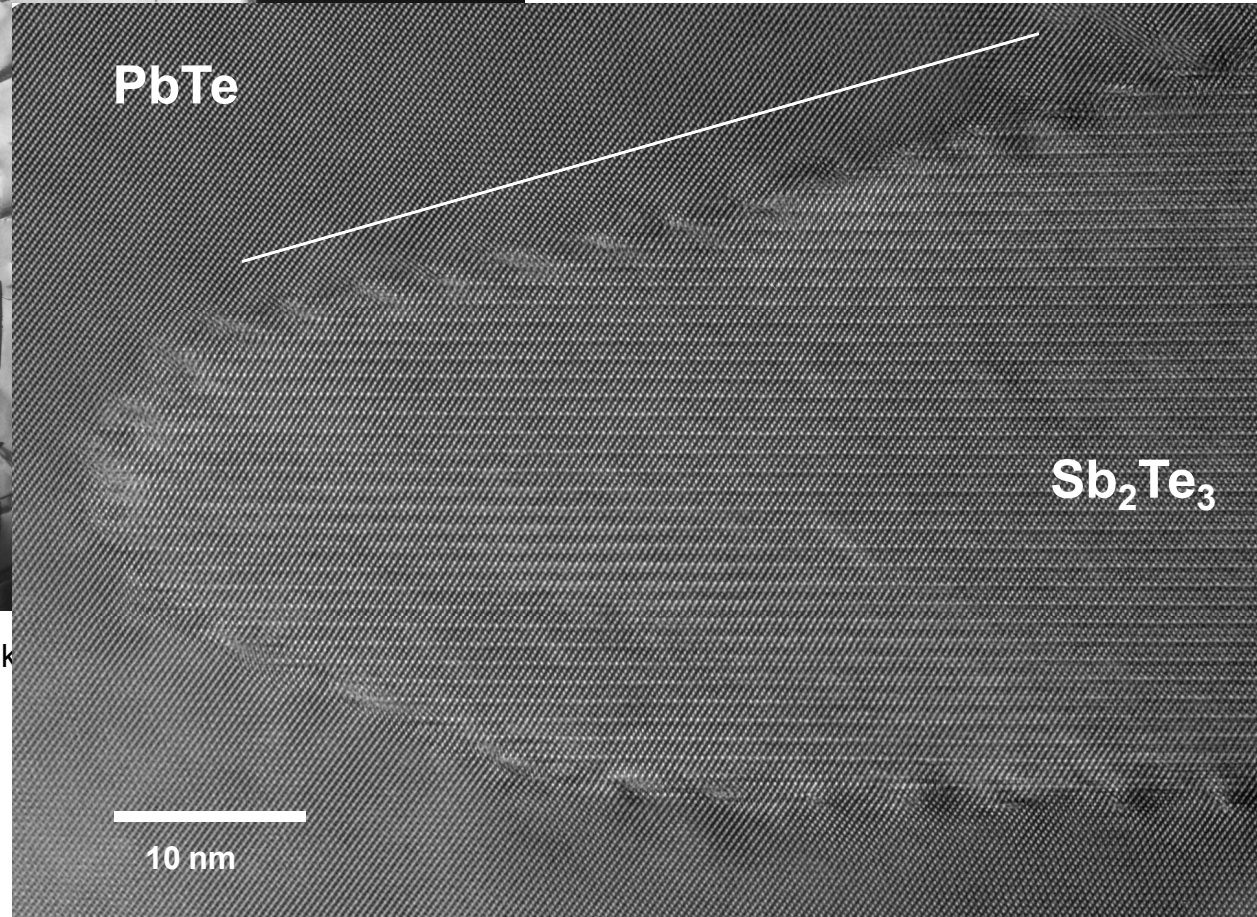
Metal rich intermediate phase

A system with larger misfit: PbTe/Sb₂Te₃

Sb₂Te₃ Precipitates in PbTe

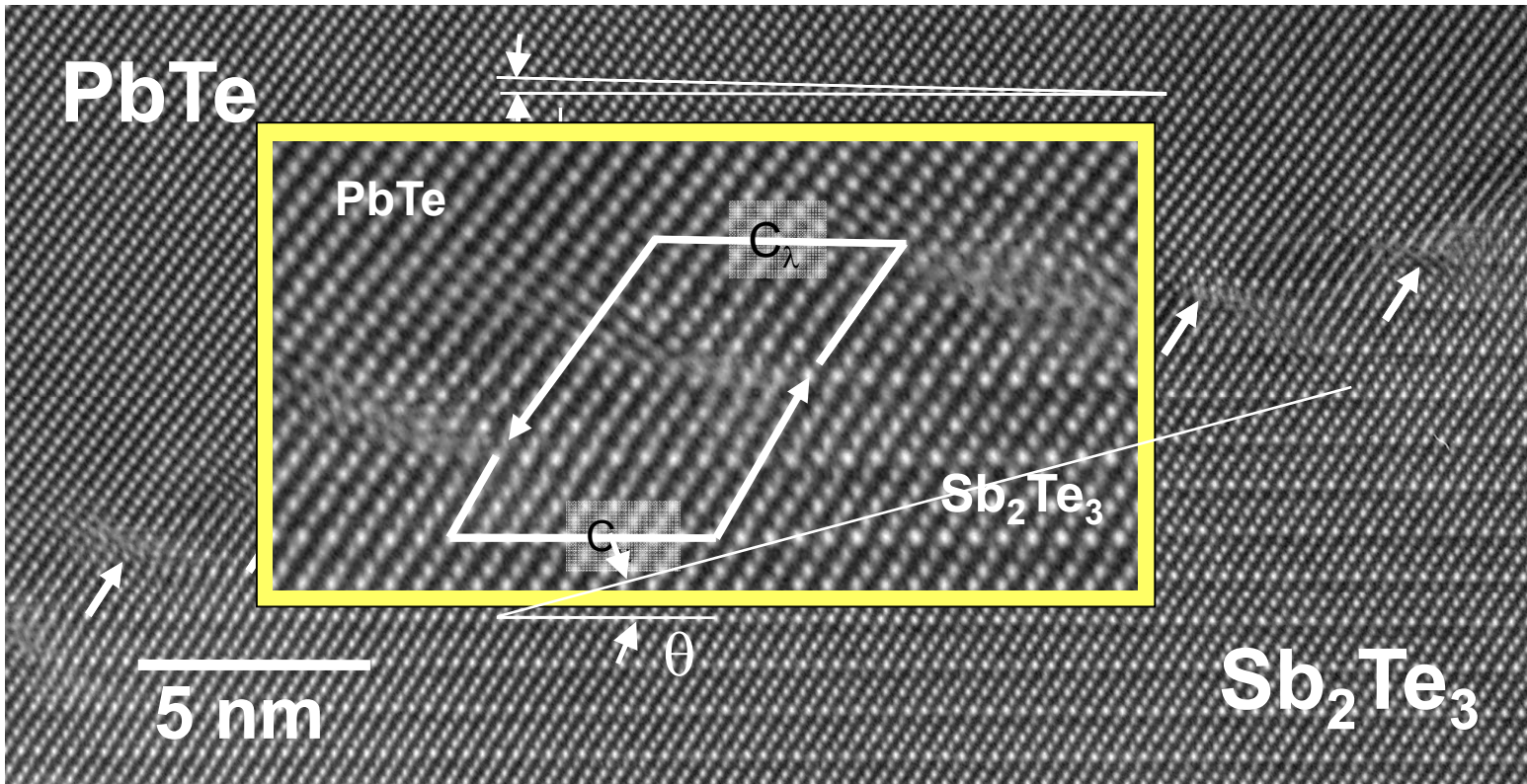


AgSbTe₂(111)/Sb₂Te₃(0001)
Misfit: +0.79%



Work with N. Heinz, T. Ik

Inclined Section of interface Composed of Disconnections



Circuit Analysis:

Defects identical to the disconnections observed in AgSbTe₂/Sb₂Te₃

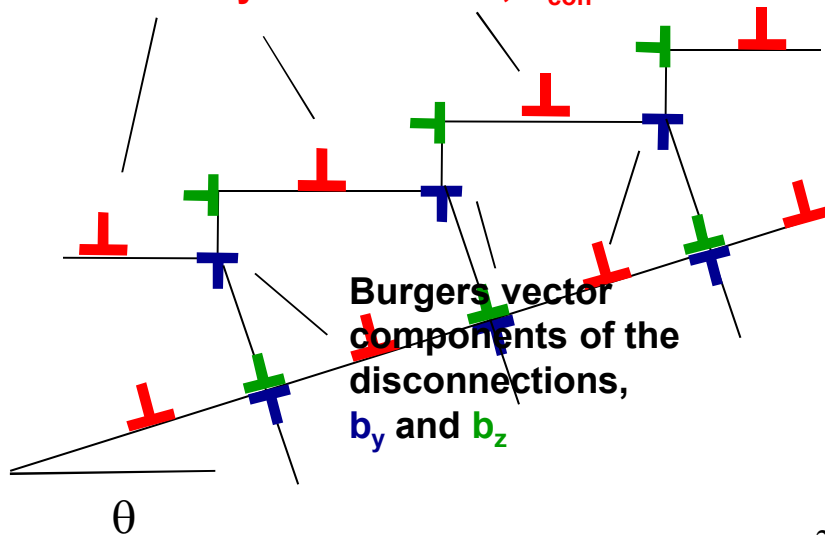
Interface Geometry:

Inclination: $\theta = 14.8^\circ$ Lattice rotation: $\phi = 1.1^\circ$ to 1.4°

Defect Spacing Controlled by Misfit Strain

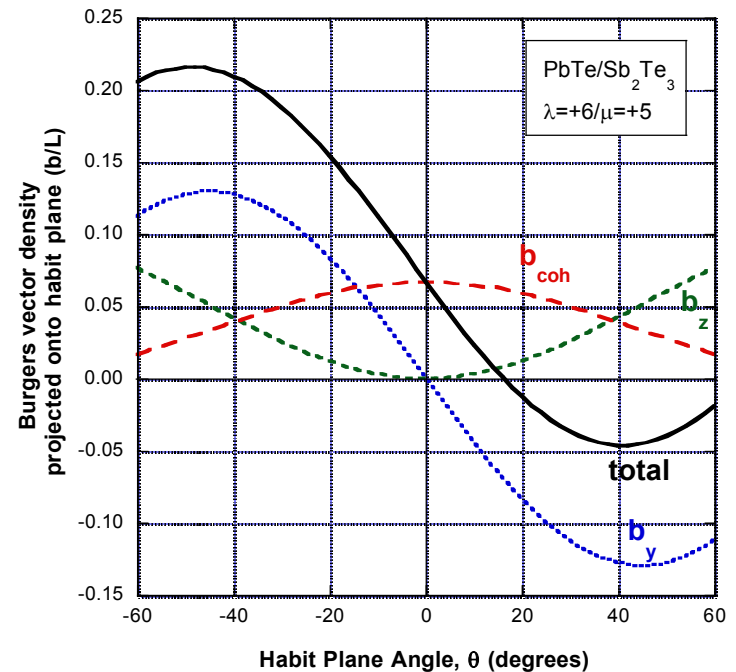
Project components on inclined interface plane

Adjust spacing to cancel (ε_{yy} = 0)
as “coherency” dislocations, b_{coh}



$$-\varepsilon = (b_y \tan \theta + b_z \tan^2 \theta) h^{-1}$$

Pond, Celotto, Hirth, Acta Mater. 2003



$$\Rightarrow \theta = 16.2^\circ$$

Out of plane **b** components produce small rotation,

$$\phi = 2 \sin^{-1} [(b_z \cos \theta - b_y \sin \theta - \varepsilon h \cos \theta) \sin \theta / 2h] \Rightarrow \phi = 1.7^\circ$$

**Steps cannot move independently:
Must be coupled through strain interaction**

Outline

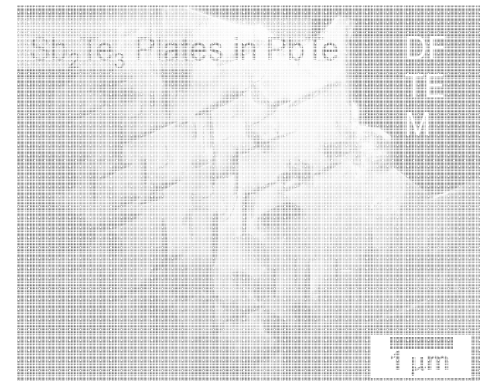
- **Rocksalt/Tetradymite Telluride Interfaces**

- AgSbTe₂/Sb₂Te₃

- PbTe/Sb₂Te₃

- Tetradymite plate formation.

- Interfacial strain accommodation.

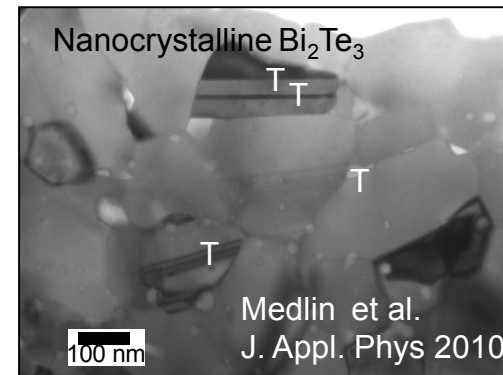


- **Structure of the basal twin in Bi₂Te₃**

- What is the compositional termination?

- Structural relaxations?

- Formation mechanism?



Bismuth Telluride

Motivation:

Large Enhancements in zT for nanostructured bulk Bi_2Te_3 (zT=1.4-1.6)

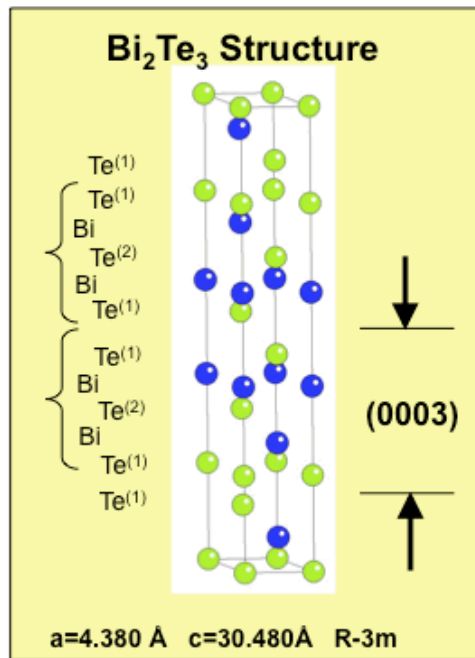
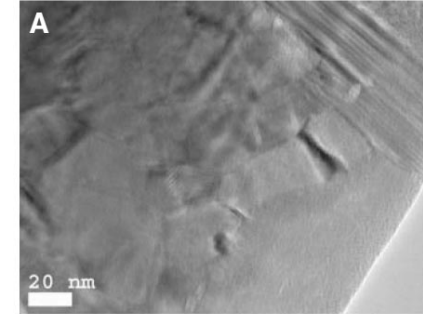
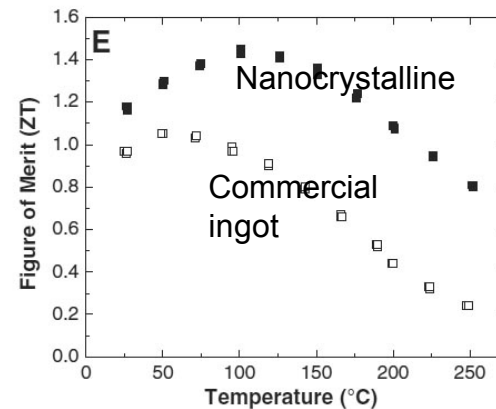
Poudel et al Science 2008 zT=1.4 @ 100°C

Xie et al, J. Appl. Phys 2009

-Reduced κ , boundary phonon scattering

Enhanced zT in nanocrystalline $(\text{Bi,Sb})_2\text{Te}_3$

Poudel et al. Science 2008



Little is known about GBs in Bi_2Te_3

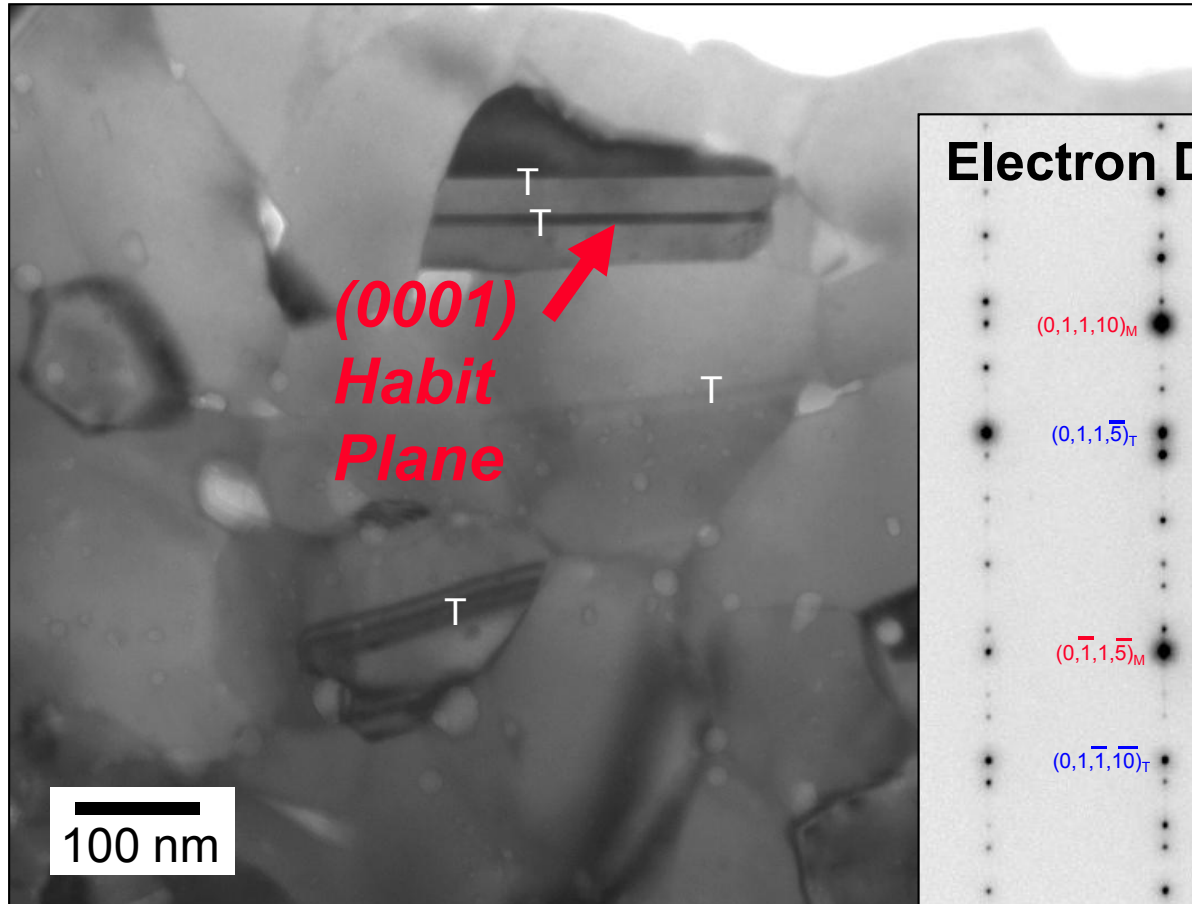
-Twins make good starting point.

Twins have potential for favorable TE electronic transport properties

-Coherent structure, near bulk-like coordination.

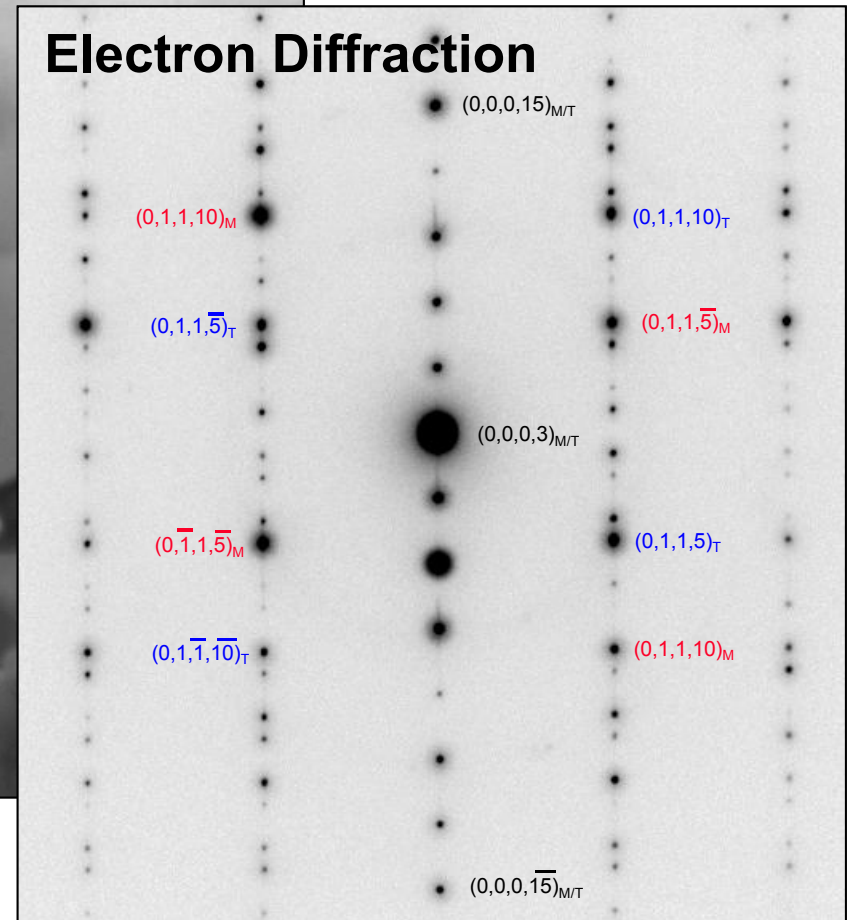
]

Twin microstructure and crystallography



Bi_2Te_3 : Powder consolidated
by spark plasma sintering

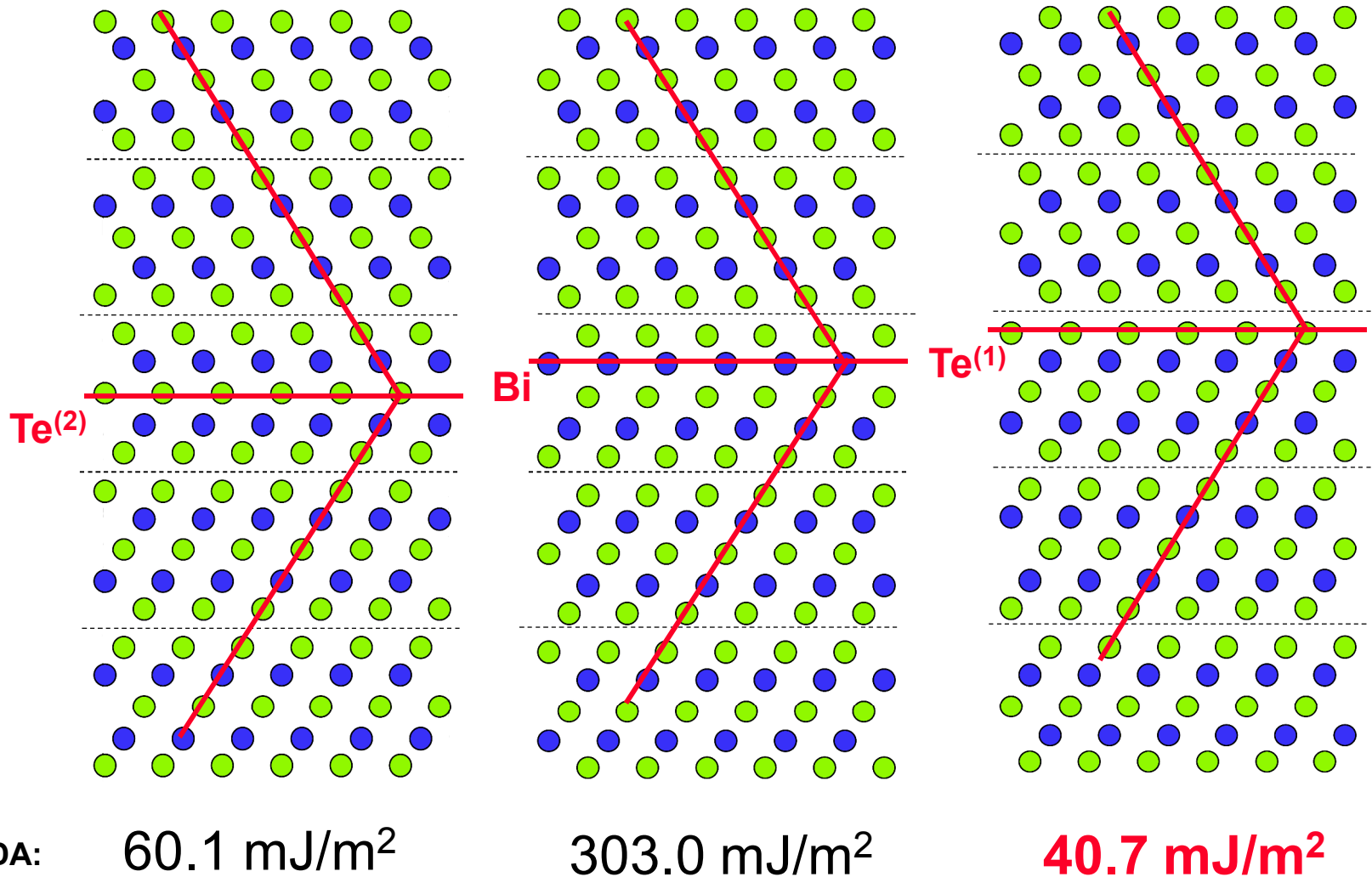
Electron Diffraction



Orientation Relationship:
 $(0001) // (0001)$
 $[2-1-10] // [-2110]$

***60° rotation
about c-axis***

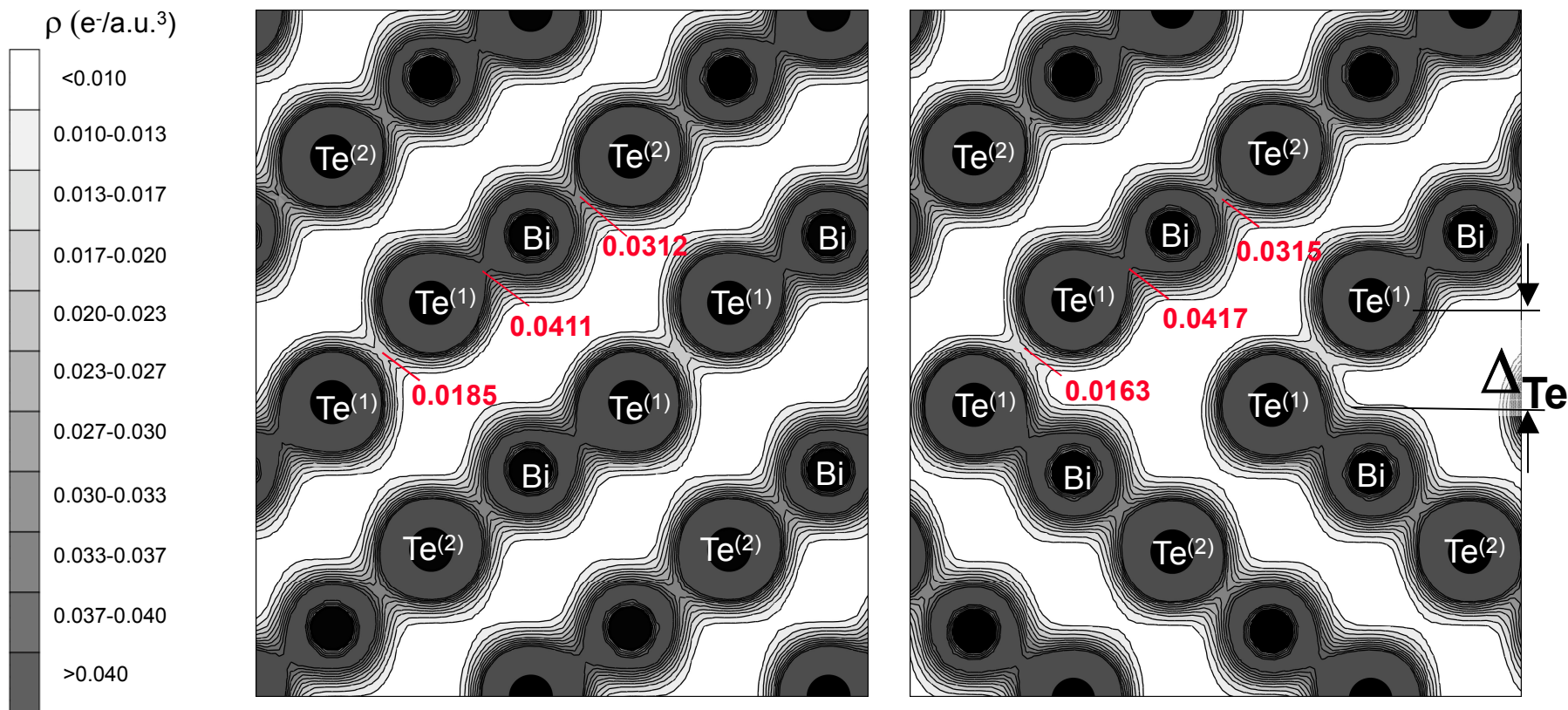
Question: How is twin terminated?



Calculations predict expansion at interface

Bi₂Te₃-Perfect Crystal

Te⁽¹⁾-Te⁽¹⁾ Twin

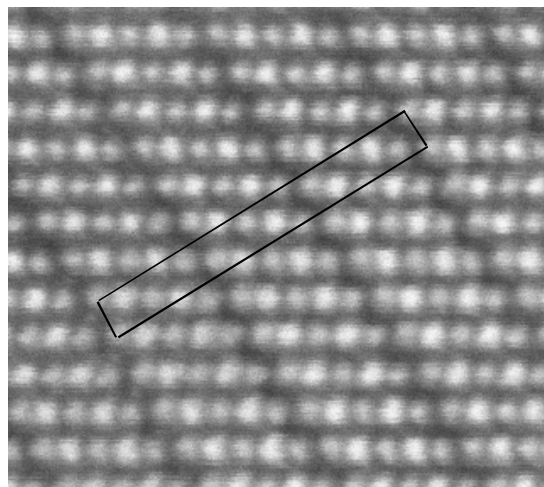
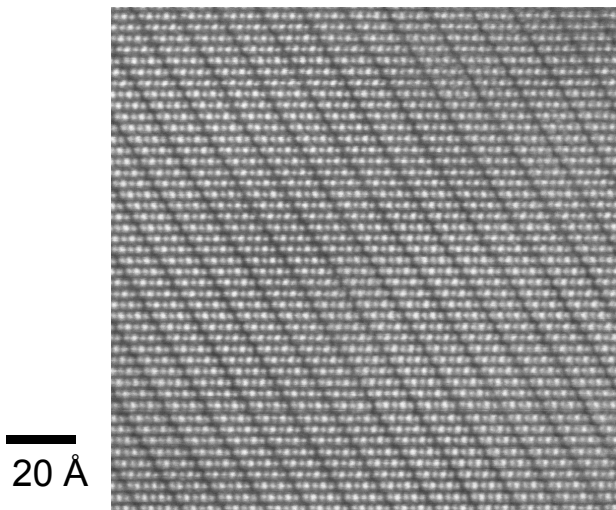


Charge density between Te⁽¹⁾-Te⁽¹⁾ atoms is lower at twin.
Calculations predict expansion normal to interface:

$$\Delta_{\text{Te,interface}} - \Delta_{\text{Te,bulk}} = +0.12\text{\AA}$$

Bi_2Te_3 : High Angle Annular Dark Field STEM

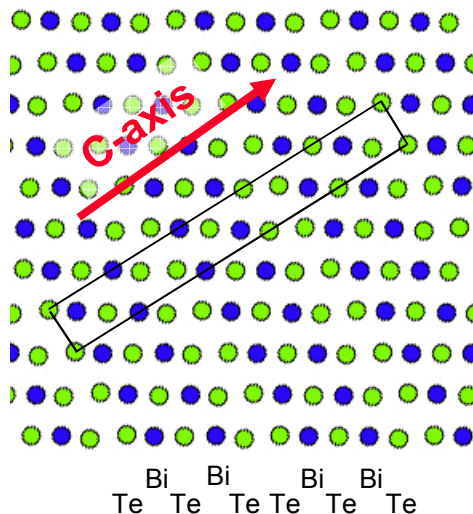
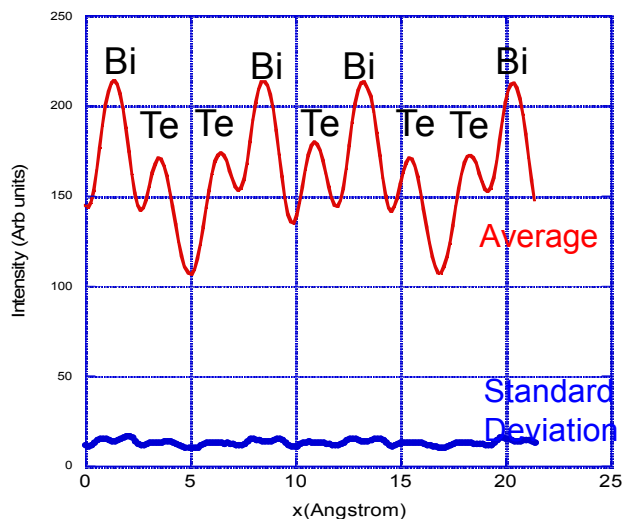
Bi_2Te_3 : $\langle 2\bar{1}\bar{1}0 \rangle$ Projection



Bi and Te are well
Discriminated by
HAADF-STEM

Bi: Z=83

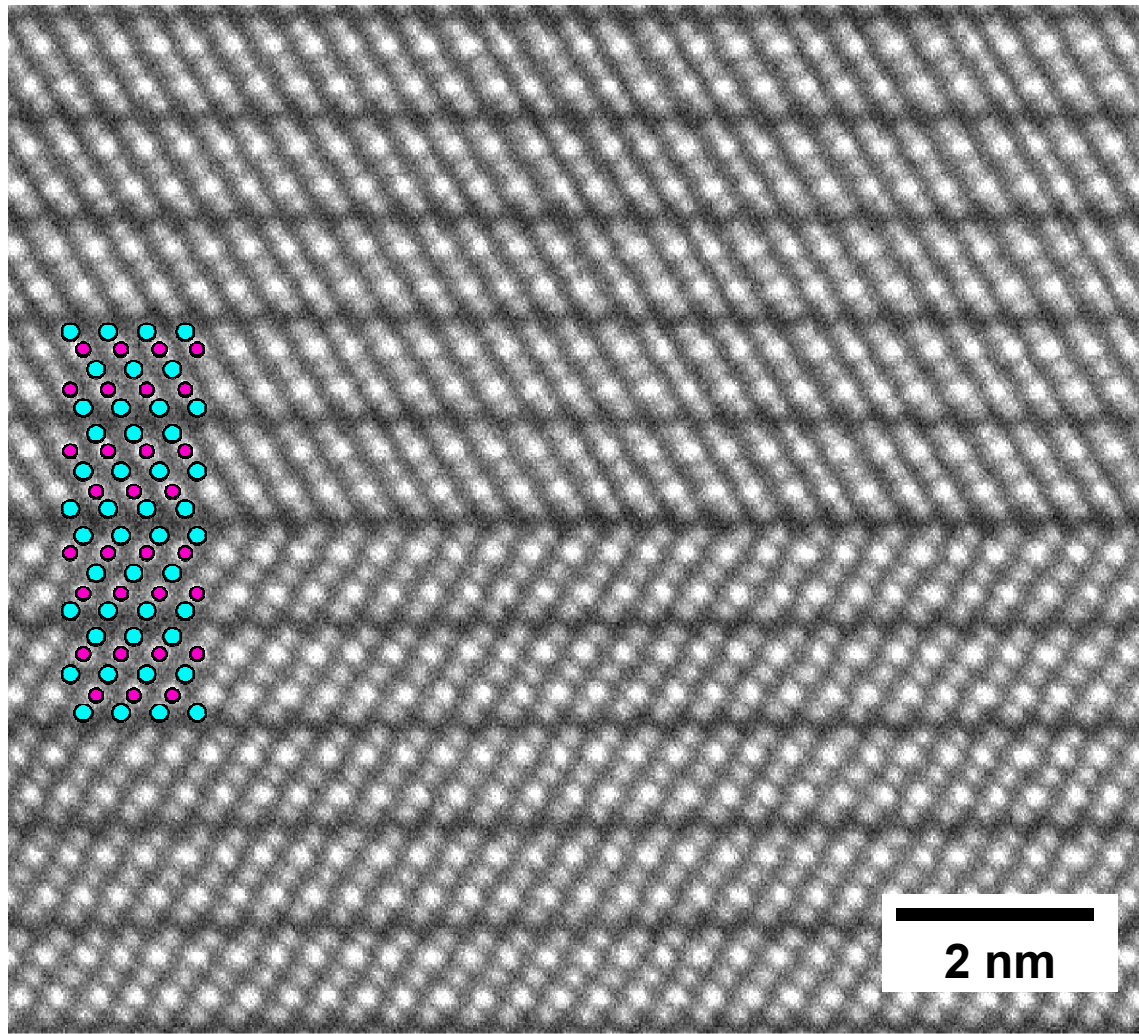
Te: Z=52



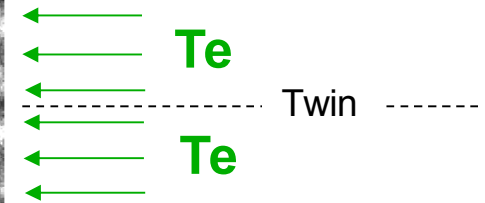
Aberration Corrected
TEAM 0.5 Instrument
National Center for
Electron Microscopy

With Quentin Ramasse

Observations: Twin terminated at $\text{Te}^{(1)}\text{-Te}^{(1)}$ layer

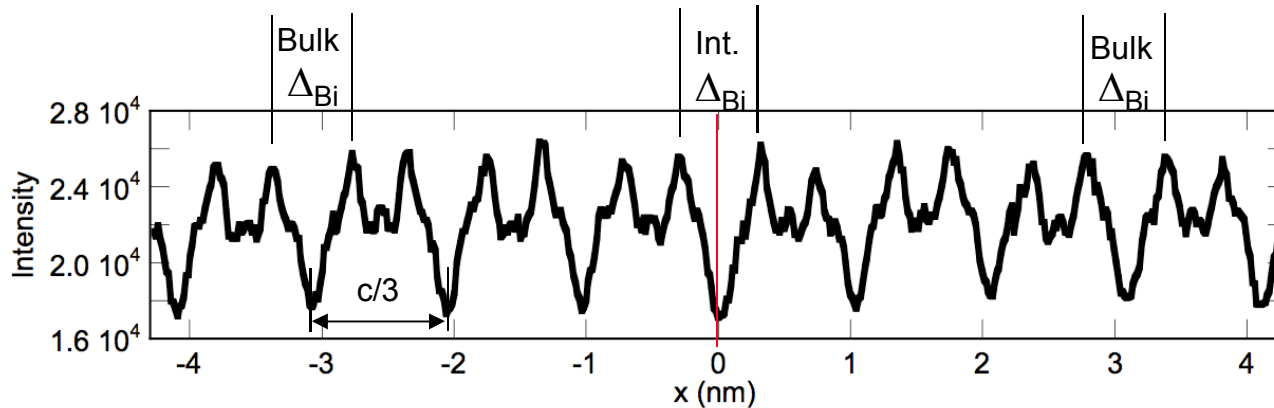


5-layer, Bi_2Te_3 packet



Experimental measurements confirm expansion

Peak positions measured from intensity line profiles



60 line profiles,
integrated over 8Å
width
4 independent images

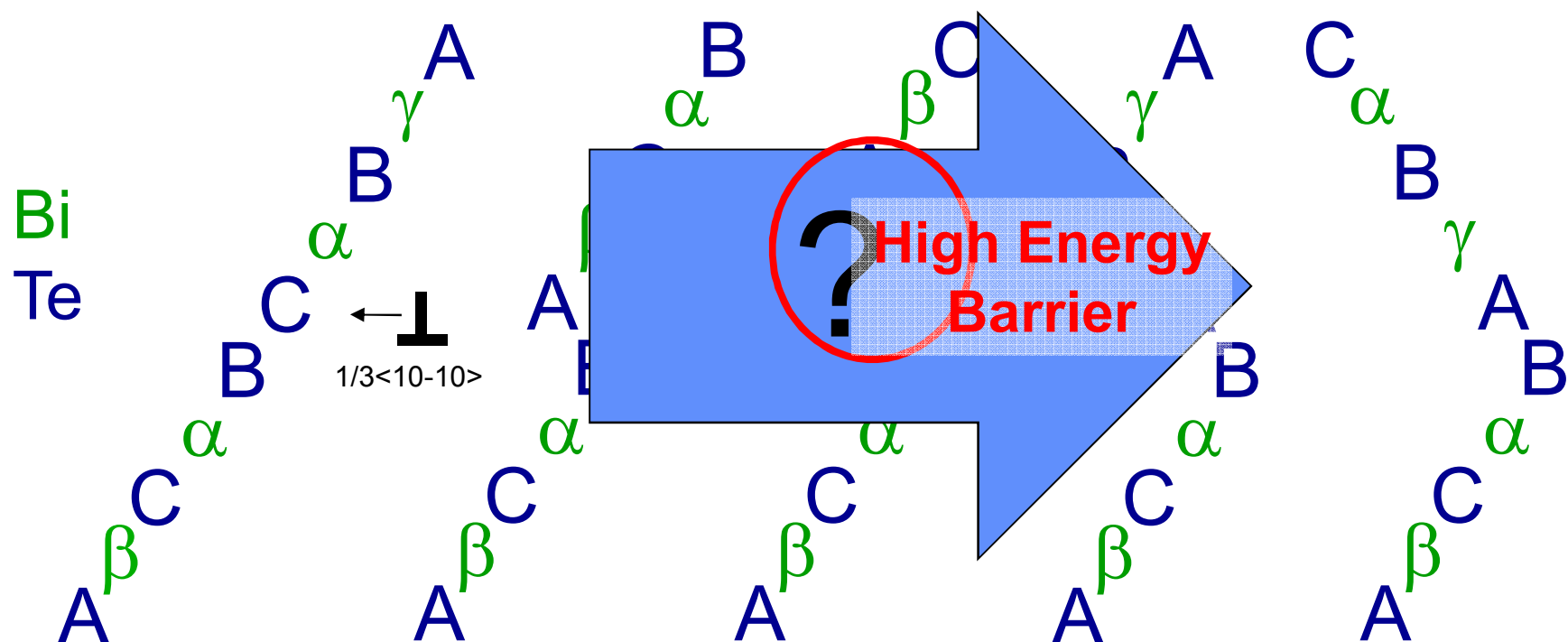
Peak positions refined by
fitting to sum of Gaussians:

$$I(x) = A_0 + \sum_{i=1}^5 A_i e^{\left[\frac{-(x-x_{0,i})^2}{2\sigma_i^2} \right]}$$

	$\Delta_{\text{int}} - \Delta_{\text{bulk}}$	
	Theory	Exp
Te ⁽¹⁾	+0.120 Å	+0.12±0.04Å
Bi	+0.116 Å	+0.13±0.03Å

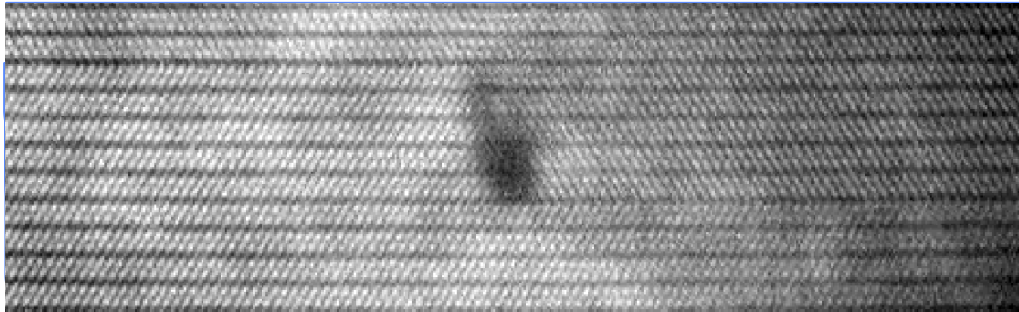
How do twins form in Bi_2Te_3 ?

Sequential motion of twinning dislocations?



- High energy barrier for Bi-terminated interface
→ independent motion of twinning dislocations unlikely.
- Alternative: Coordinated defect motion.
Groupings of *unlike* twinning dislocations

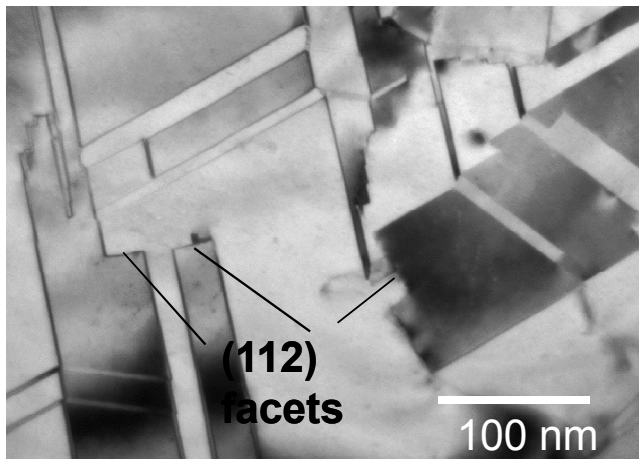
Steps in the Bi_2Te_3 Twin Boundary



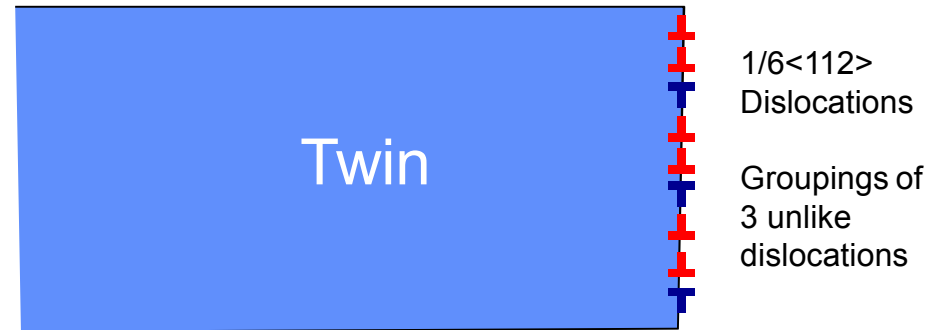
5 nm

**Analogies to
 $\{112\}$ twins in
FCC materials.**

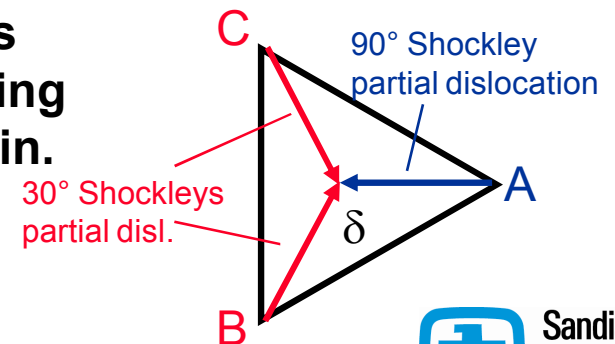
Example: Twins in Electrodeposited Ni



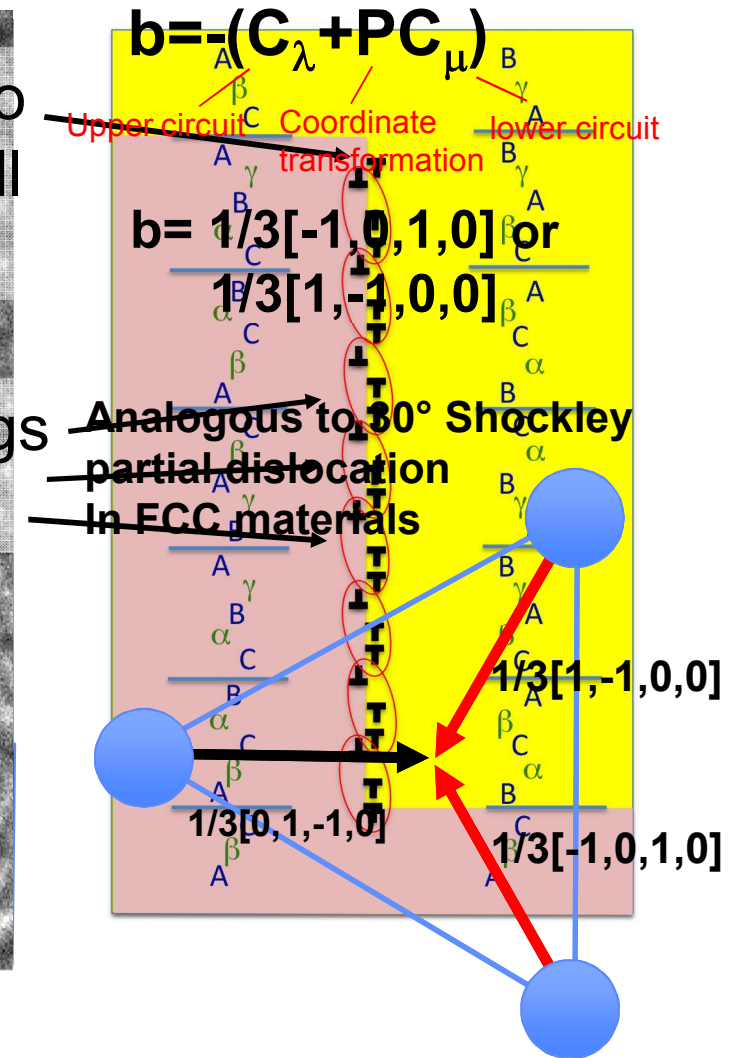
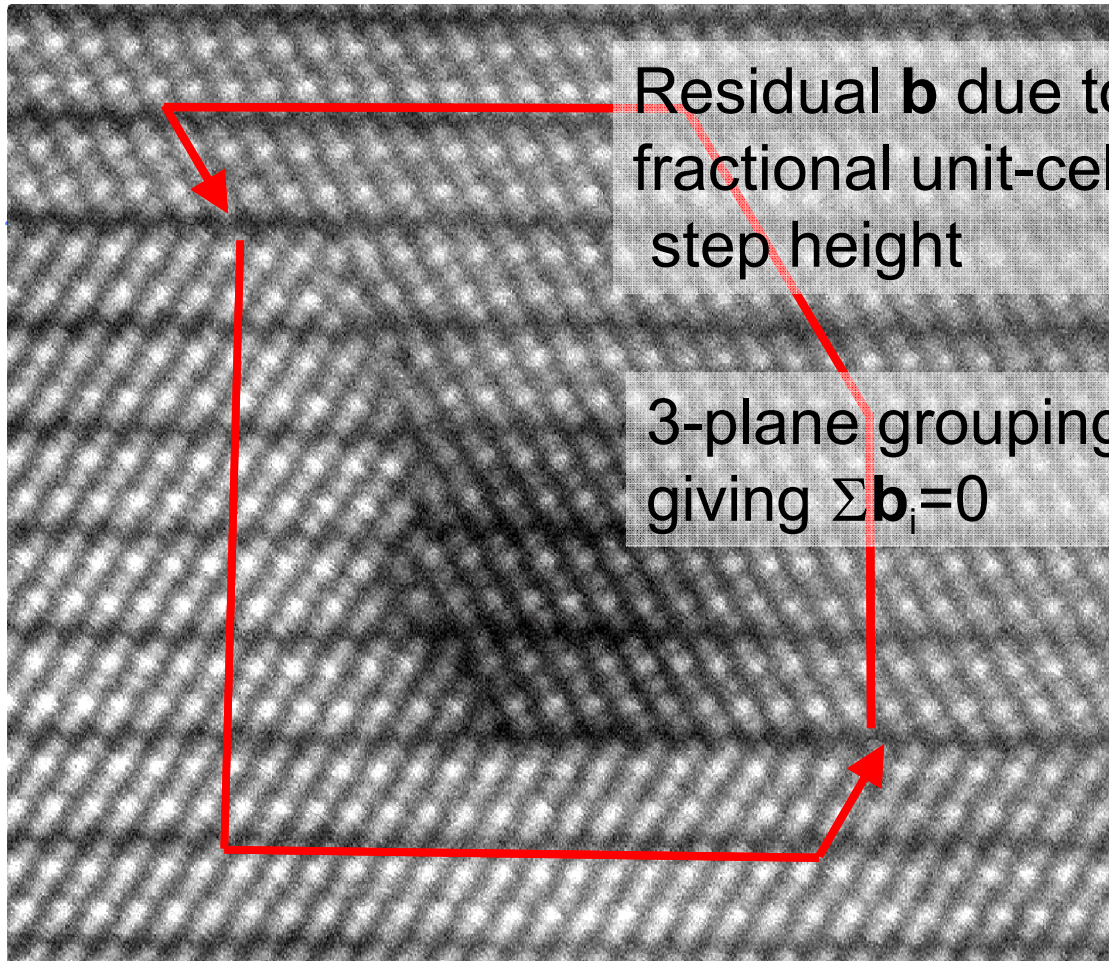
Lucadamo, Medlin, Talin, Yang, Kelly, Phil Mag 2005



**Burgers vectors
cancel eliminating
long-range strain.**



What is the dislocation content of the step?



Summary

- **Defect mechanism for tetradymite plate growth in rocksalt tellurides discovered.**
 - Disconnection motion: removes metal layer and restores stacking.
 - Interplay between misfit accommodation and interface morphology through dislocation/step character.
- **Bi₂Te₃ (0001) Twin boundary structure determined.**
 - Termination at Te(1)-Te(1) layer
 - Lowest energy structure from *ab initio* calculations
 - Structure confirmed with HAADF-STEM
 - Defect structure:
 - Analogies to FCC twins and defects.
 - chemical constraint due to energetics of interface termination.

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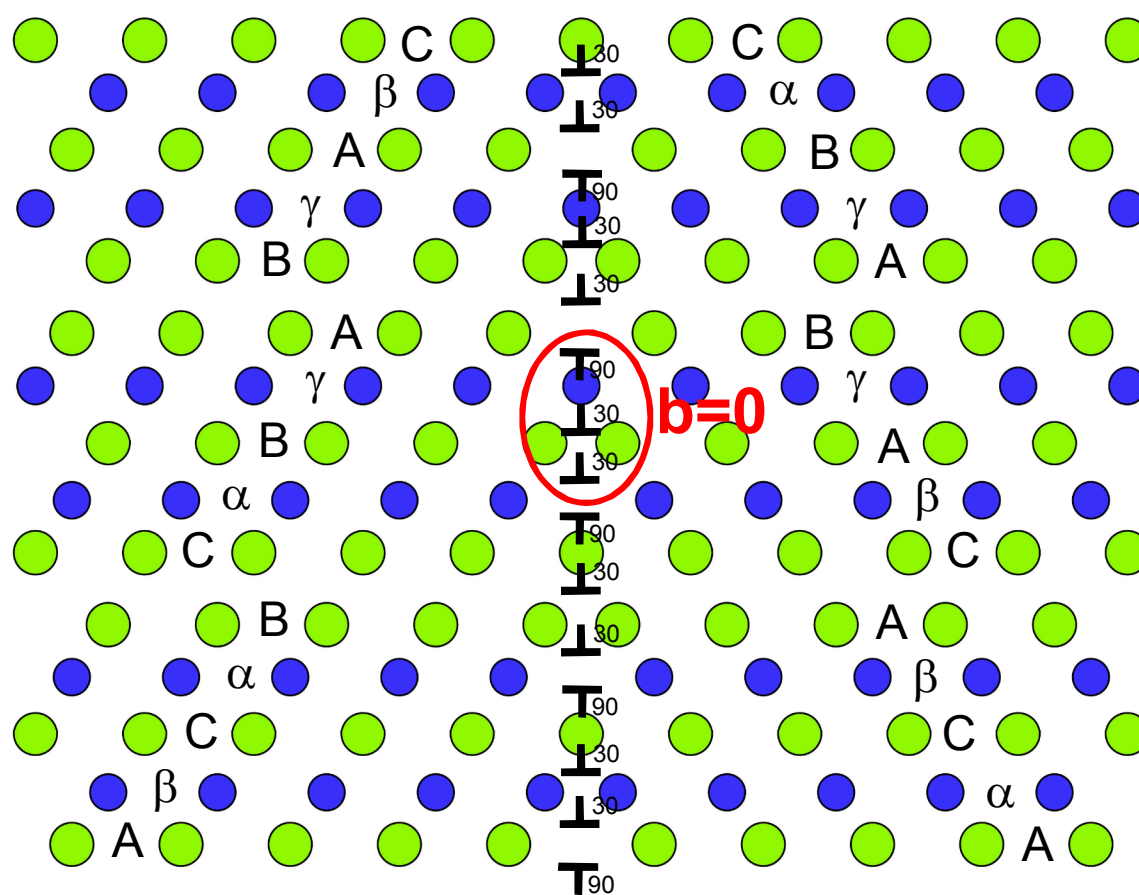
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EXTRA

Schematic of Bi_2Te_3 $\{10\text{-}10\}$ twin

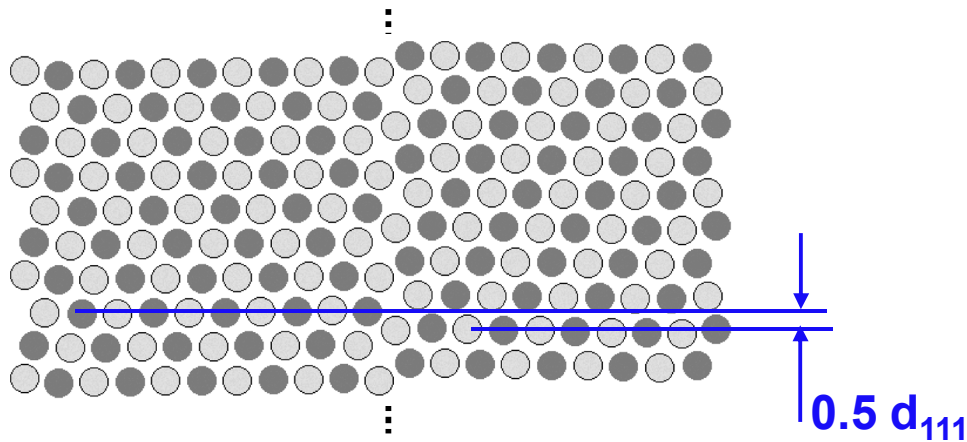


Analogous dislocation structure to FCC $\{112\}$ twin facets?

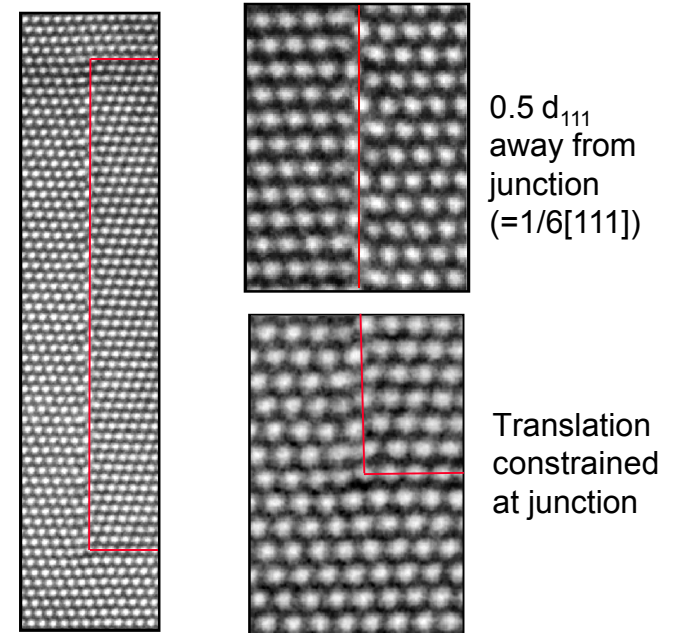
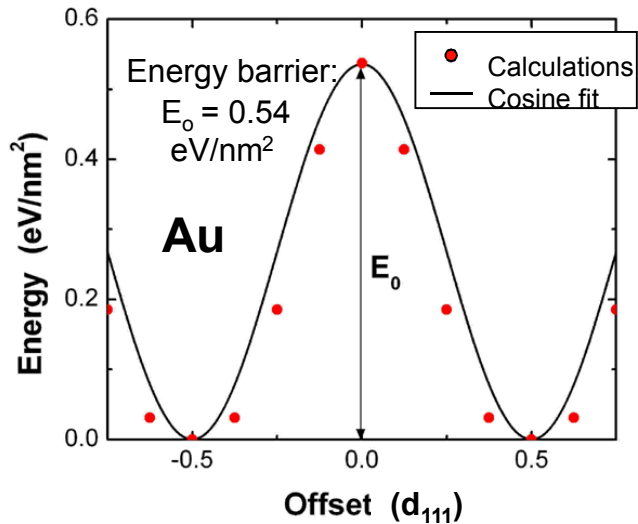
Migration by coordinated motion of 30° and 90° $1/3\langle 10\text{-}10 \rangle$ twinning dislocations

Translation of {111} planes at $\Sigma=3$ {112} Boundary

{111} Planes Offset in Unconstrained Boundary



First-principles calculations of GB energy



Dislocation-like strain field at junction

$$\mathbf{b} = 1/6[111] \\ (=1/2 \mathbf{D}\delta)$$

